NSN 5962-01-033-2288

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Between 0.745 inches and 0.785 inches

Body Width:

Between 0.240 inches and 0.260 inches

Body Height:

Between 0.095 inches and 0.140 inches

Maximum Power Dissipation Rating:

500.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Countermeasures set type an/alq-17a fscm 72314

Features Provided:

Hermetically sealed and monolithic and positive outputs and medium speed and asynchronous and presettable and synchronous and w/enable and w/clear

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

8 stage

Case Outline Source And Designator:

-0-001-ae joint electron device engineering council

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

20.5 volts power source

Memory Device Type:

Rom

Test Data Document:

81349-mil-std-883 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Ves - demil/mli

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